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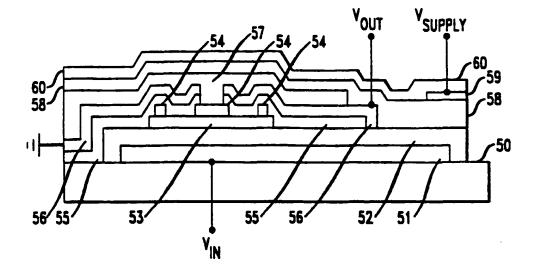
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- (54) Circuit comprising complementary thin film transistors
- (57) In preferred embodiments of the invention, the n-channel inorganic TFTs have an amorphous Si active layer (53), and the p-channel organic TFTs have  $\alpha$ -hexathienylene ( $\alpha$  6T) active layer (58). Complementary

inverters according to the invention are disclosed, as is an exemplary processing sequence that can be used to manufacture integrated complementary inverters and other complementary circuits according to the invention.

FIG. 9





## **EUROPEAN SEARCH REPORT**

Application Number

Category	Citation of document with inc of relevant passa		Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.C1.6)	
P,X	DODABALAPUR A ET AL: organic/inorganic co APPLIED PHYSICS LETT AIP, USA, vol. 68, no. 16, ISS pages 2246-2248, XPO * the whole document	omplementary circuits" ERS, 15 APRIL 1996, SN 0003-6951, 002055715	1,2,4-6	H01L51/20 H01L51/30 H01L27/12	
E	US 5 612 228 A (SHIE * column 2, line 3 - claims 1-18; figures		1,2,4-6		
A	PATENT ABSTRACTS OF JAPAN vol. 014, no. 016 (E-872), 12 January 1989 & JP 01 259563 A (MITSUBISHI ELECTRIC CORP), 17 October 1989, * abstract *		1,2,4		
D,A	DODABALAPUR A ET AL HETEROSTRUCTURE FIEI SCIENCE, vol. 269, 15 Septemi pages 1560-1562, XPO	D-EFFECT TRANSISTORS" per 1995,		TECHNICAL FIELDS SEARCHED (Int.CI.6) HOTL	
	The present search report has t	peen drawn up for all claims	}		
	Place of search	Date of completion of the search		Examiner	
THE HAGUE		16 February 1998	Kör	nigstein, C	
CATEGORY OF CITED DOCUMENTS  X: particularly relevant if taken alone Y: particularly relevant if combined with another document of the same category A technological background O: non-written disclosure P: Intermediate document		E : earlier patent do after the filling da ner D : document cited t L : document cited t	T: theory or principle underlying the invention E: earlier patent document, but published on, or after the filling date D: document cited in the application L: document cited for other reasons 8: member of the same patent family, corresponding document		

2